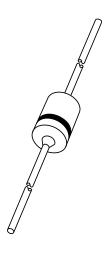
#### DISCRETE SEMICONDUCTORS

## DATA SHEET



# **BAV18 to BAV21**General purpose diodes

Product specification
Supersedes data of April 1996
File under Discrete Semiconductors, SC01

1996 Sep 17





## **General purpose diodes**

#### BAV18 to BAV21

#### **FEATURES**

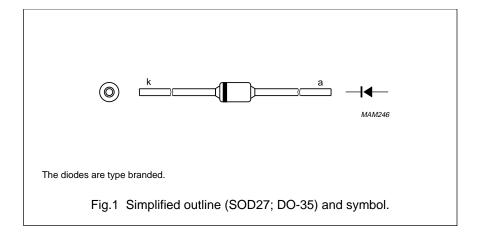
- Hermetically sealed leaded glass SOD27 (DO-35) package
- Switching speed: max. 50 ns
- · General application
- Continuous reverse voltage: max. 50 V, 100 V, 150 V, 200 V
- Repetitive peak reverse voltage: max. 60 V, 120 V, 200 V, 250 V
- Repetitive peak forward current: max. 625 mA.

#### **APPLICATIONS**

 General purposes in industrial equipment e.g. oscilloscopes, digital voltmeters and video output stages in colour television.

#### **DESCRIPTION**

The BAV18, BAV19, BAV20, BAV21 are switching diodes fabricated in planar technology, and encapsulated in hermetically sealed leaded glass SOD27 (DO-35) packages.



## General purpose diodes

BAV18 to BAV21

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage				
	BAV18		_	60	V
	BAV19		_	120	V
	BAV20		_	200	V
	BAV21		_	250	V
V <sub>R</sub>	continuous peak reverse voltage				
	BAV18		_	50	V
	BAV19		_	100	V
	BAV20		_	150	V
	BAV21		_	200	V
I <sub>F</sub>	continuous forward current	see Fig.2; note 1	_	250	mA
I <sub>FRM</sub>	repetitive peak forward current		_	625	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	9	A
		t = 100 μs	_	3	А
		t = 1 s	_	1	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	_	400	mW
T <sub>stg</sub>	storage temperature		-65	+175	°C
Tj	junction temperature		_	175	°C

#### Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

## General purpose diodes

BAV18 to BAV21

#### **ELECTRICAL CHARACTERISTICS**

 $T_j$  = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 100 mA	_	1.0	V
		I <sub>F</sub> = 200 mA	_	1.25	V
$I_R$	reverse current	see Fig.5			
		$V_R = V_{Rmax}$	_	100	nA
		$V_R = V_{Rmax}$ ; $T_j = 150 ^{\circ}C$	_	100	μΑ
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}$ ; $V_R = 0$ ; see Fig.6	ı	5	pF
t <sub>rr</sub>	reverse recovery time	when switched from I <sub>F</sub> = 30 mA to	_	50	ns
		$I_R$ = 30 mA; $R_L$ = 100 $\Omega$ ; measured at $I_R$ = 3 mA; see Fig.8			

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	lead length 10 mm; note 1	375	K/W

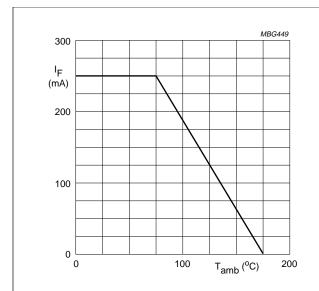
#### Note

1. Device mounted on a printed circuit-board without metallization pad.

## General purpose diodes

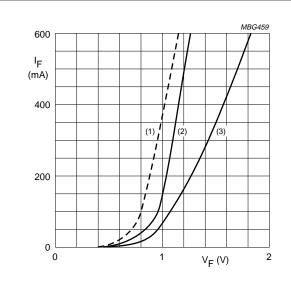
#### BAV18 to BAV21

#### **GRAPHICAL DATA**



Device mounted on an FR4 printed-circuit board; lead length 10 mm.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1)  $T_j = 150$  °C; typical values.
- (2)  $T_j = 25$  °C; typical values.
- (3)  $T_j = 25$  °C; maximum values.

Fig.3 Forward current as a function of forward voltage.

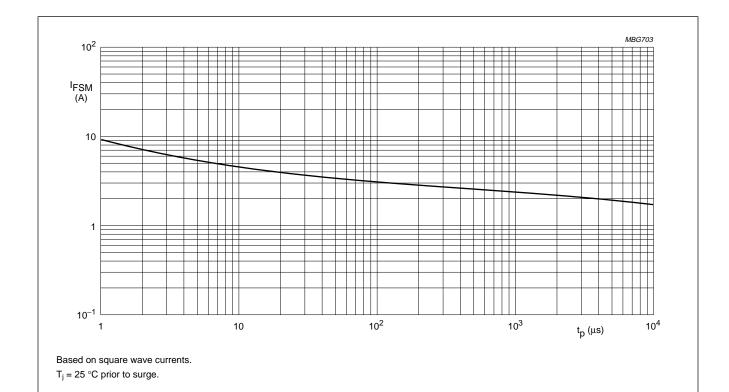


Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

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1.6

1.4

1.2

1.0

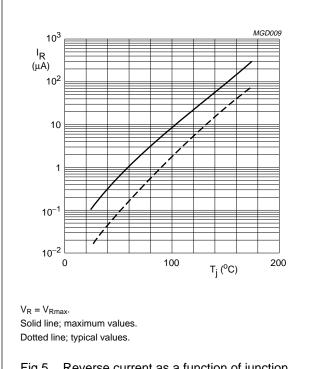
(pF)

## General purpose diodes

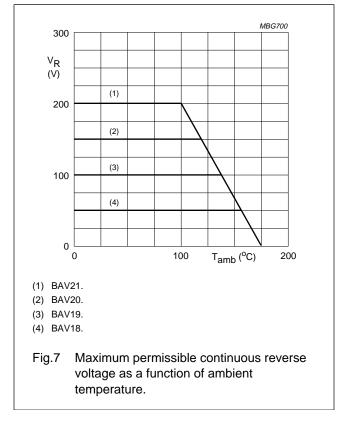
### BAV18 to BAV21

MGD005

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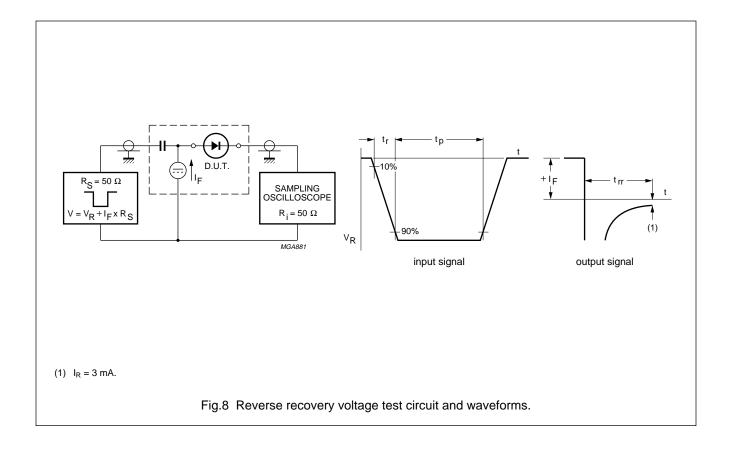


8.0 10  $V_{R}(V)$  $f = 1 \text{ MHz}; T_j = 25 \,^{\circ}\text{C}.$ Reverse current as a function of junction Fig.6 Diode capacitance as a function of reverse temperature. voltage; typical values.



## General purpose diodes

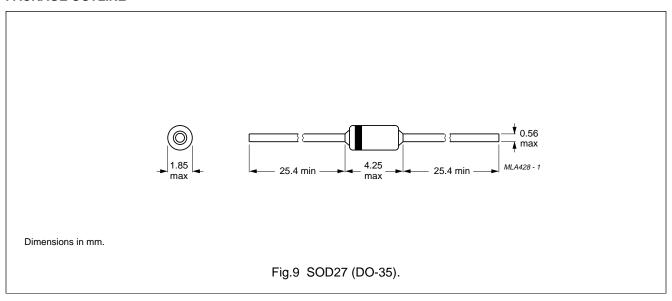
## BAV18 to BAV21



## General purpose diodes

BAV18 to BAV21

#### **PACKAGE OUTLINE**



#### **DEFINITIONS**

Data Sheet Status		
Objective specification	This data sheet contains target or goal specifications for product development.	
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.	
Product specification	This data sheet contains final product specifications.	
Limiting values		
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.		

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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